TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM3K324R

- O Power Management Switch Applications
- O DC-DC Converter

Unit: mm

•	1	9	R	V	'n	ri	ve

• Low ON-resistance: $R_{DS(ON)} = 56 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.5 V)}$

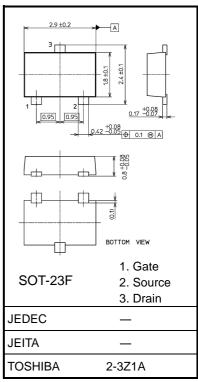
: $R_{DS(ON)} = 72 \text{ m}\Omega \text{ (max) (@V_{GS} = 2.5 V)}$

 $: R_{DS(ON)} = 109 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.8 V)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol		Rating	Unit	
Drain-source voltage		V_{DSS}		30	V	
Gate-source voltage		V _{GSS}		±12	V	
Drain current	DC	I _D (Note 1)		4.0	А	
	Pulse	I _{DP} (Note 1,2)		10	A	
Power dissipation		P _D (Note 3)		1	W	
			t ≦ 10s	2	VV	
Channel temperature		T _{ch}		150	°C	
Storage temperature range		T _{stg}		-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 11 mg (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: The channel temperature should not exceed 150°C during use.

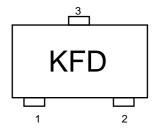
Note 2: PW ≤ 10ms, Duty ≤ 1%

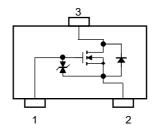
Note 3: Mounted on a FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: } 645 \text{ mm}^2)$

Marking

Equivalent Circuit (top view)





Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

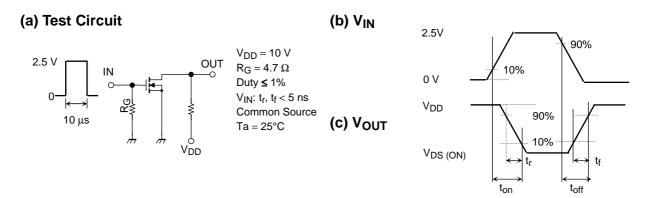
Thermal resistance R_{th} (ch-a) and power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	$V_{(BR)DSS}$ $I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$		30	_	_	V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	18	_	_		
Drain cut-off curre	ent	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V		_	_	1	μА
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±10	μА
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$		0.4	_	1.0	V
Forward transfer admittance		Yfs	$V_{DS} = 3 \text{ V}, I_{D} = 2.0 \text{ A}$	(Note 4)	_	10.5	_	S
Drain-source ON-resistance			$I_D = 2.0 \text{ A}, V_{GS} = 4.5 \text{ V}$	(Note 4)	_	45	56	mΩ
		R _{DS (ON)}	I _D = 1.0 A, V _{GS} = 2.5 V	(Note 4)	_	55	72	
			I _D = 0.5 A, V _{GS} = 1.8 V	(Note 4)	_	69	109	
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		_	200	_	pF
Output capacitance		C _{oss}			_	40	_	
Reverse transfer capacitance		C _{rss}	<u></u>	_	13	_		
Total gate charge		Qg	$-V_{DS} = 10 \text{ V}, I_{D} = 2.4 \text{ A}$ $-V_{GS} = 4.5 \text{ V}$		_	2.2	_	nC
Gate-source charge		Q _{gs1}			_	0.5	_	
Gate-drain charge		Q _{gd}			_	0.9	_	
Switching time	Turn-on time	t _{on}	$V_{DD} = 10 \text{ V}, I_D = 2.0 \text{ A},$ $V_{GS} = 0 \text{ to } 2.5 \text{V}, R_G = 4.7 \Omega$		_	9	_	ns
	Turn-off time	t _{off}			_	9.5	_	
Drain-source forward voltage		V _{DSF}	$I_D = -4.0 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 4)		_	-0.8	-1.2	V

Note 4: Pulse test.

Note 5: If a reverse bias is applied between gate and source, this device enters V(BR)DSX mode. Note that the drain-source breakdown voltage is lowered in this mode.

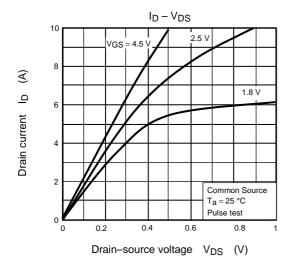


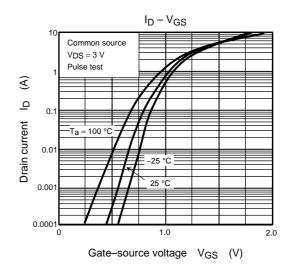
Usage Considerations

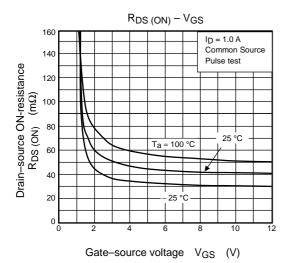
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the SSM3K324R). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

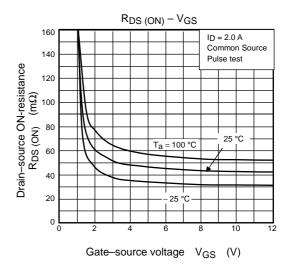
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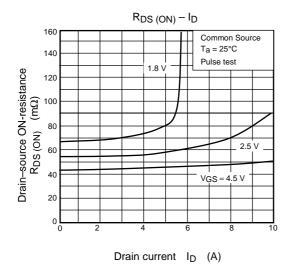
Take this into consideration when using the device.

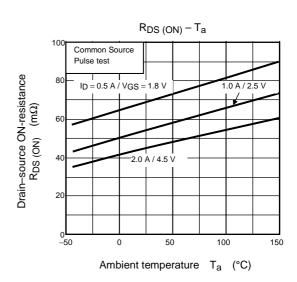




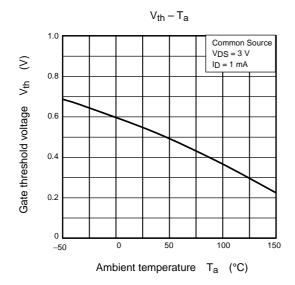


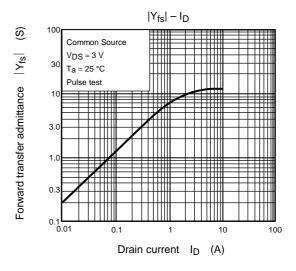


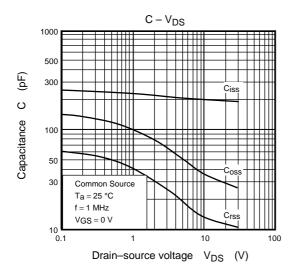


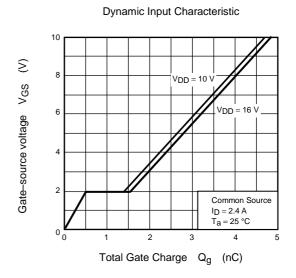


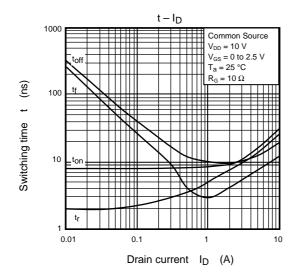
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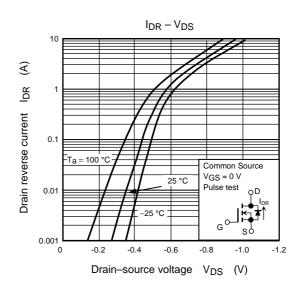


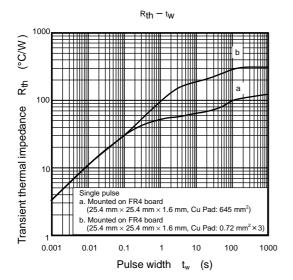


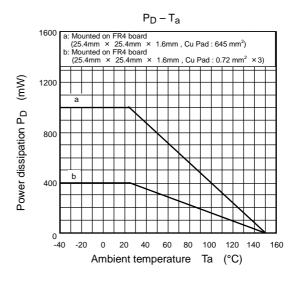












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